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Low Energy Photon Filter Box Optimization Study for the Gamma Irradiation Facility (GIF)

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ABSTRACT

As a follow-up to results presented at the 16th International Symposium on Reactor Dosimetry, a new set of low energy photon filter box designs were evaluated for potential testing at the Gamma Irradiation Facility in Sandia National Laboratories' Technical Area V. The goal of this filter box design study is to produce the highest fidelity gamma ray test environment for electronic parts. Using Monte Carlo coupled photon/electron transport, approximately a dozen different designs were evaluated for the effectiveness in reducing the dose enhancement in a silicon sensor. The completion of this study provides the Radiation Metrology Laboratory staff with a starting point for experimental test plans that could lead to improvement in the gamma ray test environment at the Gamma Irradiation Facility.

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1. INTRODUCTION

Experimenters in Sandia National Laboratories photon and mixed (neutron/gamma) field test facilities rely on the calibrated thermoluminescent dosimeters (TLDs) to provide accurate measurements of the photon dose. One of the principal means of reducing the gamma dose measurement uncertainty in Sandia National Laboratories' (SNL) reactor environments is careful calibration of the $\text{CaF}_2\text{:Mn}$ TLDs used in the test environment [1]. Almost all Co-60 gamma fields used for TLD calibration have a low energy photon component that hampers the ability to obtain high quality calibrations, and the Gamma Irradiation Facility (GIF) at SNL is no different. The scattered photons that make up the low energy photon component are a principal source of measurement error for the TLD calibration. The low energy photon component also contributes significantly to the difficulty in accurately translating results provided by dosimetry results to the radiation dose experienced by the devices under test. ASTM E1249, Standard Practice for Minimizing Dosimetry Errors in Radiation Hardness Testing of Silicon Electronics Devices Using Co-60 Sources, describes a method that utilizes photon spectrum filter boxes to enclose devices under test that can reduce the measurement error during TLD calibration as well as during normal radiation testing of electronic components in the gamma field [2].

1.1. Background

The dosimetry error created by low energy photon dose enhancement is minimized by the use of a lead/aluminum (Pb/Al) filter box [2]. The dose enhancement reduction is accomplished by photon spectrum hardening, and the spectrum hardening is accomplished by irradiating the TLDs (or device under test) in filter boxes that have an outer layer of between 1.5 mm and 2.0 mm of Pb and an inner of between 0.7 mm and 1.0 mm of Al [2]. When dosimetrists at the Radiation Metrology Laboratory (RML) noted that the standard Pb/Al filter boxes in use at the GIF (1.6 mm of Pb, 3.2 mm of Al) were outside the guidelines of the standard, an optimization study was performed to determine if the current filter boxes might be improved [3]. The optimization study used a silicon sensor that is representative of a CMOS-7 technology, and the stack-up of materials for the silicon sensor is found in Table 1.

1.2. Previous Results

After extensive calculations with MCNP6 [4], three-layer filter box designs performed no better than two-layer designs [3]. Thus, the future work portion of the optimization paper highlighted a series of additional filter box design options that were based on two-layer designs. This report is a follow-up to the calculations performed at 1 meter from the GIF Cell 3 single pin source. As with other studies, the previous work on Co-60 filter boxes at the GIF defined the dose enhancement factor (DEF) as the ratio of the absorbed dose to the electronic equilibrium dose (that is, kerma) at the location or material of interest [3], [5] – [7]. Building on DePriest *et al.* [3], the filter box effectiveness metric for this study will be the silicon DEF in the active silicon layer. The DEF values obtained during the optimization study at 1 meter from the source are found in Table 2.

The previous work suggested examining lead/copper, bismuth/copper, tantalum/aluminum, and tantalum/copper filter box designs as well as additional lead/aluminum and tungsten/copper designs. This document provides a description and summary of the examination of these filter box designs.

Table 1 – Stack-up of Materials for CMOS-7 Silicon Sensor

Disc Number	Material Layer	Disc Thickness (cm)
1	Tin/Lead (63/37) solder	0.06
2	Copper	0.0015
3	Nickel	0.0005
4	Gold	0.00007
5	BT-Epoxy Laminate	0.036
6	Copper	0.0015
7	Nickel	0.0005
8	Gold	0.00007
9	Ablebond 8361J	0.003
10	P-type Silicon	0.03
11	Silicon Oxide (SiO ₂)	0.00002
12	Active Silicon Layer	0.000025
13	Tungsten	0.000085
14	Silicon Oxide (SiO ₂) Passivation Layer	0.000838
15	Plastic Encapsulation Layer	0.0866

Table 2 – GIF Cell 3 Dose Enhancement Factors Reported in Reference [3]

Filter Box Details	Density Thickness (g/cm ²)	DEF in Active Silicon Layer	Dose Reduction Ratio
None	0.00	2.02	---
*1.59 mm Pb / 3.18 mm Al	2.66	1.34	0.57
1.52 mm W / 1.60 mm Al	3.37	1.43	0.59
1.27 mm W / 1.25 mm Cu	3.57	1.27	0.52
1.52 mm W / 0.75 mm Cu	3.61	1.23	0.50
1.25 mm Cu / 3.18 mm Al	1.98	1.60	0.75
3.18 mm Cu / 3.18 mm Al	3.70	1.52	0.67
*This is the current filter box utilized by the RML.			

2. CALCULATION DESCRIPTION

Over the past 17 years, staff members in the Applied Nuclear Technologies organization in Tech Area V (TA-V) at SNL have developed and improved a MCNP radiation transport model of GIF Cell 3. Using the latest version of the transport model, Filter box designs were placed at a location 1.0 meter from the location used for the single pin source of GIF Cell 3. Figure 1 shows an overhead view of the radiation transport model while Figure 2 displays the side view. Figure 3 provides an enlarged view to show the source pin details and the relationship between the source and the filter box. The filter box design is a 10 cm cube of air with the filtering materials of the appropriate thickness layered around the cube. The low atomic number material is the first layer around the air followed by the high atomic number material.

```
08/21/18 10:34:03
GIF Cell #3 -- Filter Box
Optimization Testing - Deck #1

probid = 08/21/18 10:24:41
basis: XY
( 1.000000, 0.000000, 0.000000)
( 0.000000, 1.000000, 0.000000)
origin:
( 67.94, -46.62, 25.40)
extent = ( 800.00, 800.00)
```

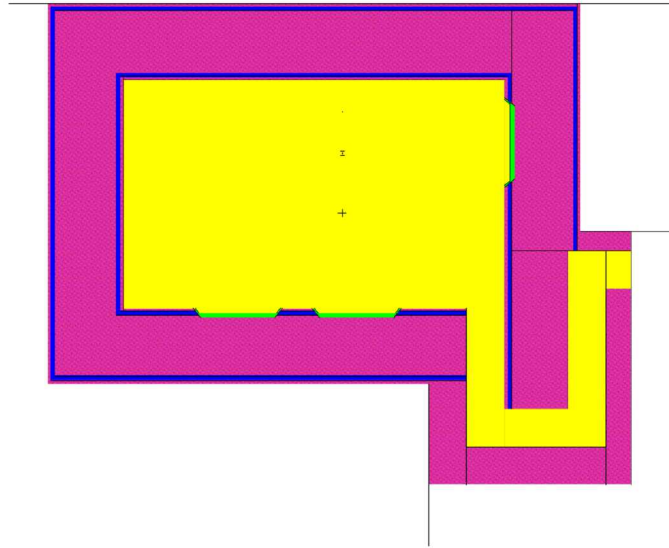


Figure 1 – Overhead View of GIF Cell 3 MCNP Model

The silicon sensor based on CMOS-7 technology was modeled and placed inside the filter box. The silicon sensor was oriented such that the tungsten layer closest to the active silicon layer faced the source pin based on the recommendations found in ASTM E1249 [2]. In addition to the silicon sensor, a 1 cm radius sphere of air was modeled inside the filter box to tally the energy spectrum of the photons that are transported through the box.

```

08/21/18 09:17:28
GIF Cell #3 -- Filter Box
Optimization Testing - Deck #1

probid = 08/21/18 08:58:47
basis: YZ
( 0.000000, 1.000000, 0.000000)
( 0.000000, 0.000000, 1.000000)
origin:
( 67.94, -46.62, 25.40)
extent = ( 800.00, 800.00)

```

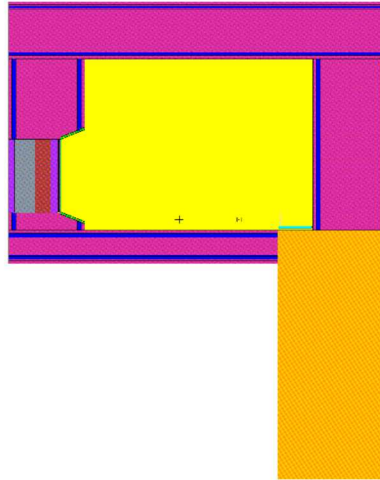


Figure 2 – Side View of GIF Cell 3 MCNP Model

Once the modeling was completed, a full 3D coupled photon/electron transport calculation was performed with MCNP6 using the Serrano High Performance Computing (HPC) platform at SNL. To assess the DEF in the silicon sensor (and other metrics), the following quantities were tallied for each of the filter boxes under study:

- Average silicon photon kerma in the active silicon region
- Energy deposition (collision heating) in the active silicon region
- Energy-dependent photon fluence in the scoring sphere

The Monte Carlo simulations were run until the energy deposition tally (dose tally) obtained a relative error of between 4 to 6%. The relative errors for the other tallies were typically less than 1% as the dose tally had the most difficulty in convergence. The filter box configurations examined in this report are found in Table 3.

08/21/18 10:42:03
GIF Cell #3 -- Filter Box
Optimization Testing - Deck #1

probid = 08/21/18 10:34:36
basis: YZ
(0.000000, 1.000000, 0.000000)
(0.000000, 0.000000, 1.000000)
origin:
(67.94, 96.62, 25.40)
extent = (125.00, 125.00)

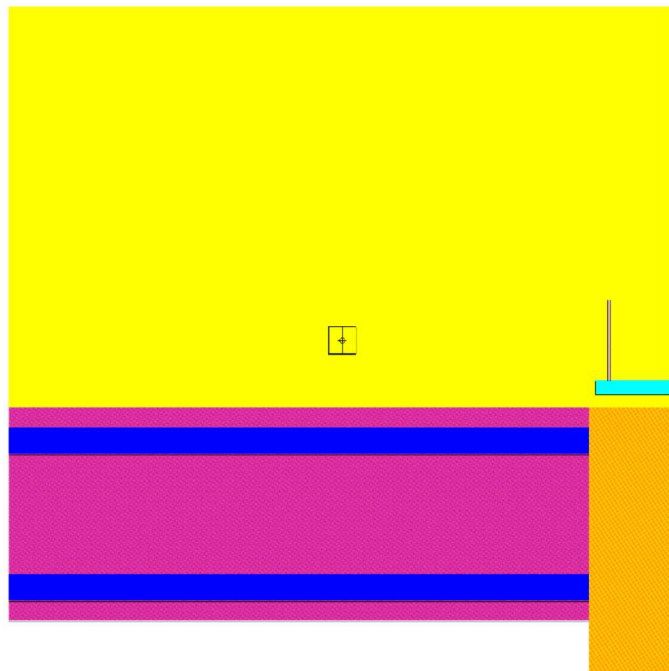


Figure 3 – Enlarged Side View of GIF Cell 3 MCNP Model with Filter Box

Table 3 – Filter Box Details

Filter Box Details	Density Thickness (g/cm²)
1.587 mm Pb / 0.686 mm Cu	2.42
1.587 mm Pb / 0.813 mm Cu	2.53
1.587 mm Pb / 1.016 mm Cu	2.71
1.981 mm Pb / 0.813 mm Cu	2.98
2.387 mm Pb / 0.813 mm Cu	3.44
3.175 mm Pb / 0.813 mm Cu	4.33
1.5875 mm Bi / 0.813 mm Cu	2.28
3.175 mm Bi / 0.813 mm Cu	3.82
4.7625 mm Bi / 0.813 mm Cu	5.37
1.016 mm Ta / 0.813 mm Cu	2.39
1.270 mm Ta / 0.813 mm Cu	2.81
1.524 mm Ta / 0.813 mm Cu	3.23
2.032 mm Ta / 0.813 mm Cu	4.06
1.524 mm W / 2.540 mm Al	3.63
1.524 mm W / 3.175 mm Al	3.80
1.524 mm W / 4.064 mm Al	4.04
1.524 mm W / 0.686 mm Cu	3.56
1.524 mm W / 0.813 mm Cu	3.67
1.524 mm W / 1.016 mm Cu	3.85

3. FILTER BOX CALCULATION RESULTS

The results of the GIF Cell 3 filter box calculations are found in Table 4. The values for the DEF in the active silicon layer are consistent with the previous work. The data in the table clearly suggests that copper is a better low atomic number filter material than aluminum. Additionally, the 20-gauge copper (that is, 32 mil or 0.813 mm) appears to be the optimum thickness to use whether it is coupled with lead or tungsten. [NOTE: The lead and tungsten filters were completed first, so the 20-gauge copper was the only thickness used for the bismuth and tantalum filter box designs.]

Table 4 – GIF Cell 3 Dose Enhancement Factors for Various Filter Boxes

Filter Box Details	Density Thickness (g/cm ²)	DEF in Active Silicon Layer	Dose Reduction Ratio
1.587 mm Pb / 0.686 mm Cu	2.42	1.25	0.53
1.587 mm Pb / 0.813 mm Cu	2.53	1.22	0.52
1.587 mm Pb / 1.016 mm Cu	2.71	1.27	0.53
1.981 mm Pb / 0.813 mm Cu	2.98	1.24	0.51
2.387 mm Pb / 0.813 mm Cu	3.44	1.22	0.49
3.175 mm Pb / 0.813 mm Cu	4.33	1.27	0.49
1.5875 mm Bi / 0.813 mm Cu	2.28	1.32	0.57
3.175 mm Bi / 0.813 mm Cu	3.82	1.31	0.52
4.7625 mm Bi / 0.813 mm Cu	5.37	1.33	0.49
1.016 mm Ta / 0.813 mm Cu	2.39	1.25	0.54
1.270 mm Ta / 0.813 mm Cu	2.81	1.23	0.52
1.524 mm Ta / 0.813 mm Cu	3.23	1.25	0.52
2.032 mm Ta / 0.813 mm Cu	4.06	1.19	0.48
1.524 mm W / 2.540 mm Al	3.63	1.32	0.54
1.524 mm W / 3.175 mm Al	3.80	1.40	0.57
1.524 mm W / 4.064 mm Al	4.04	1.36	0.55
1.524 mm W / 0.686 mm Cu	3.56	1.20	0.49
1.524 mm W / 0.813 mm Cu	3.67	1.20	0.49
1.524 mm W / 1.016 mm Cu	3.85	1.22	0.50

To understand the effects of the filter materials on the photon spectrum inside a filter box, the photon spectrum inside a subset of the boxes was calculated along with a spectrum for a bare (or unfiltered) silicon sensor. The photon spectrum for the bare silicon sensor is found in Figure 4. In the spectrum, the “notch” or bump around 0.20 MeV represents the backscatter peak (Compton edge) for the Co-60 gammas. The Compton scatter peak as a function of scattering angle for Co-60 gamma energies is found in Figure 5. The photon spectrum inside the 1.524 mm W / 0.813 mm Cu filter box is found in Figure 6, and it is plotted with the unfiltered spectrum. The photon spectra inside the 1.587 mm Pb / 0.813 mm Cu and 2.032 mm Ta / 0.813 mm Cu filter boxes are found in

Figure 7 and Figure 8, respectively. These figures provide some insight into why the DEF is improved from an electronic testing perspective compared to the unfiltered environment.

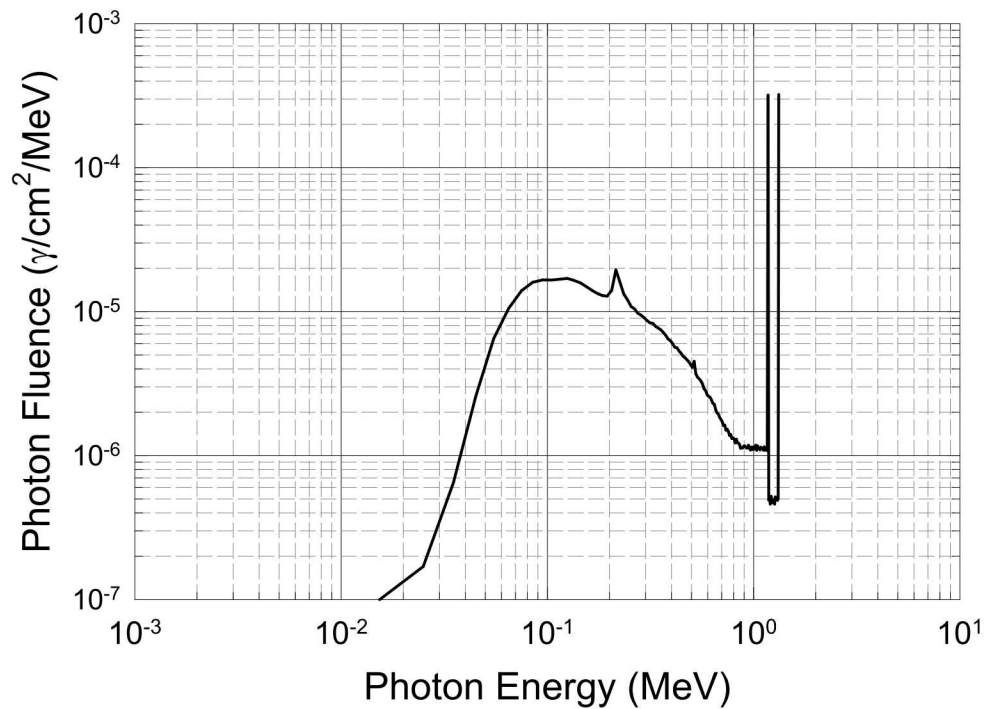


Figure 4 – Unfiltered Photon Spectrum @ 1 m from Single Pin Source in Cell 3

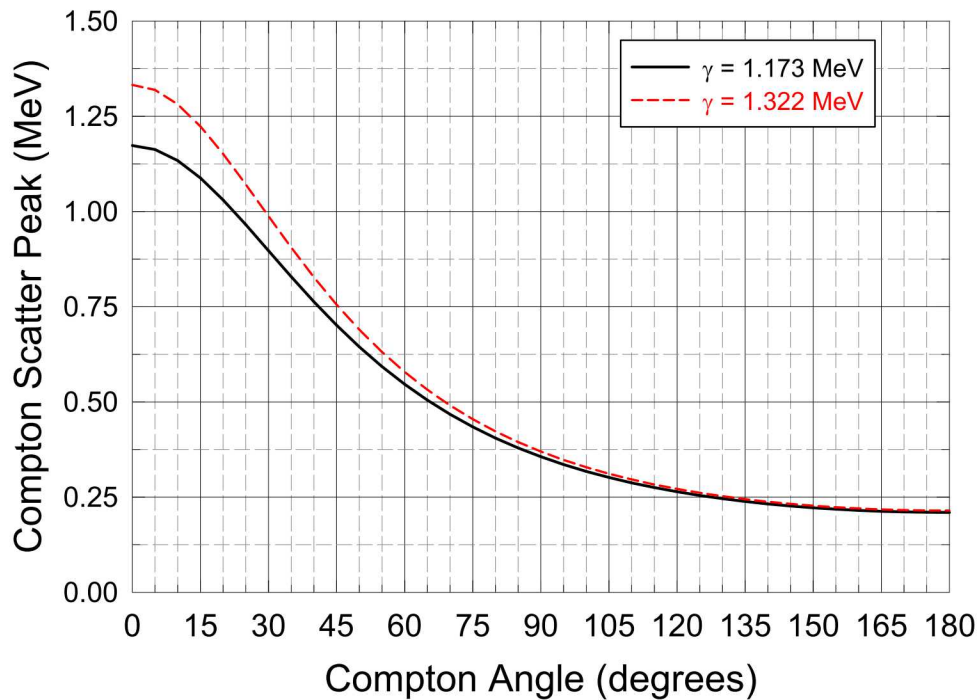


Figure 5 – Compton Edge as a Function of Scattering Angle

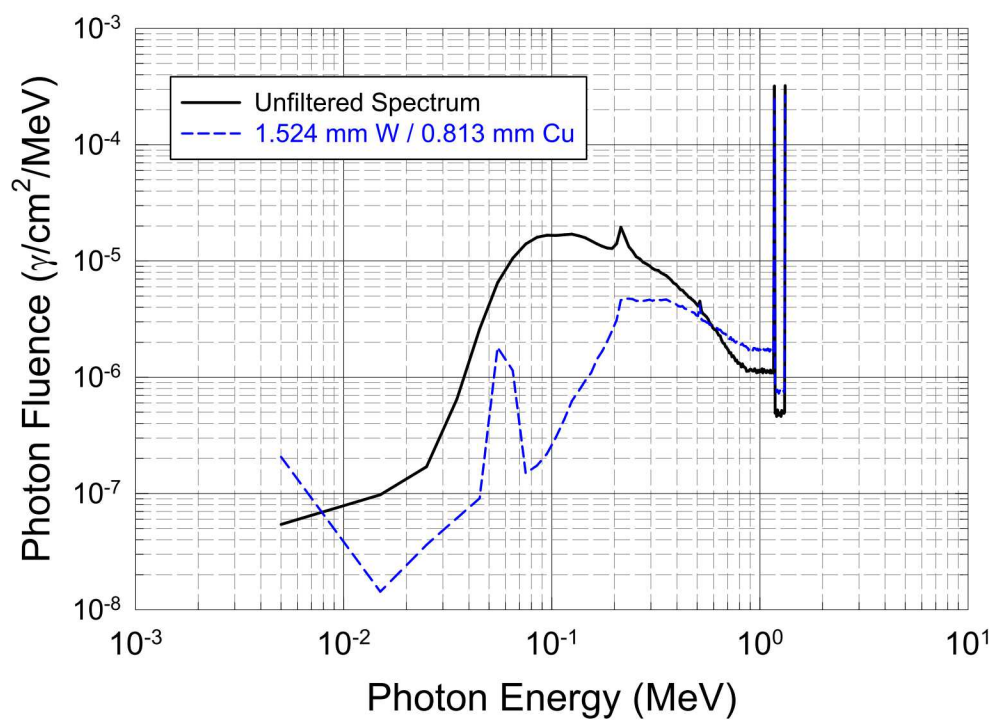


Figure 6 – Photon Spectrum with 1.524 mm W / 0.813 mm Cu Filter

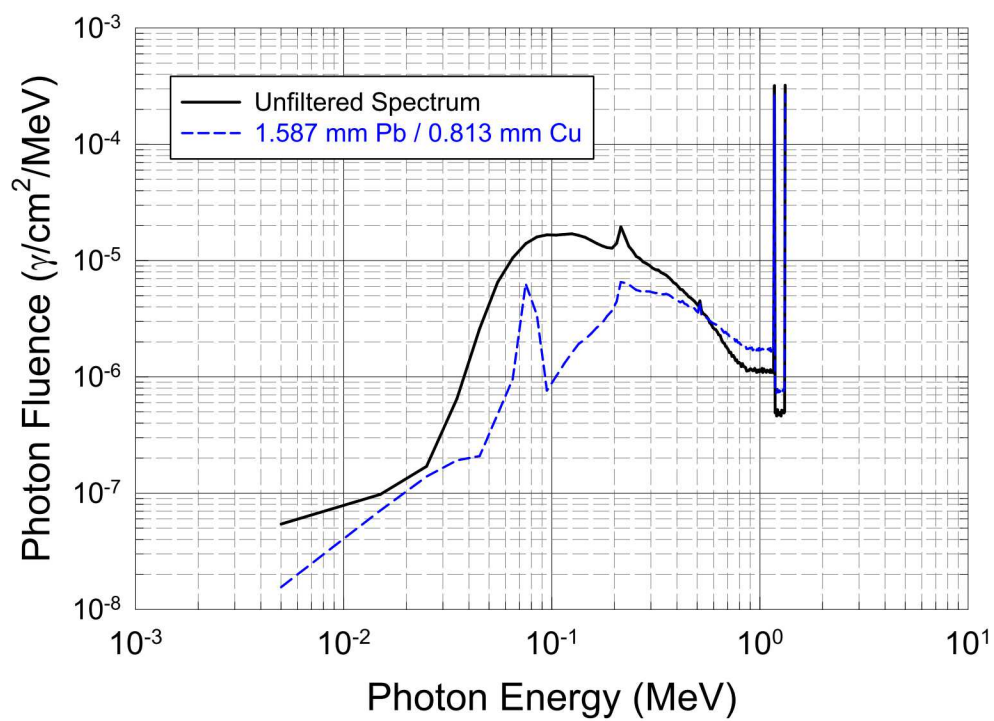


Figure 7 – Photon Spectrum with 1.587 mm Pb / 0.813 mm Cu Filter

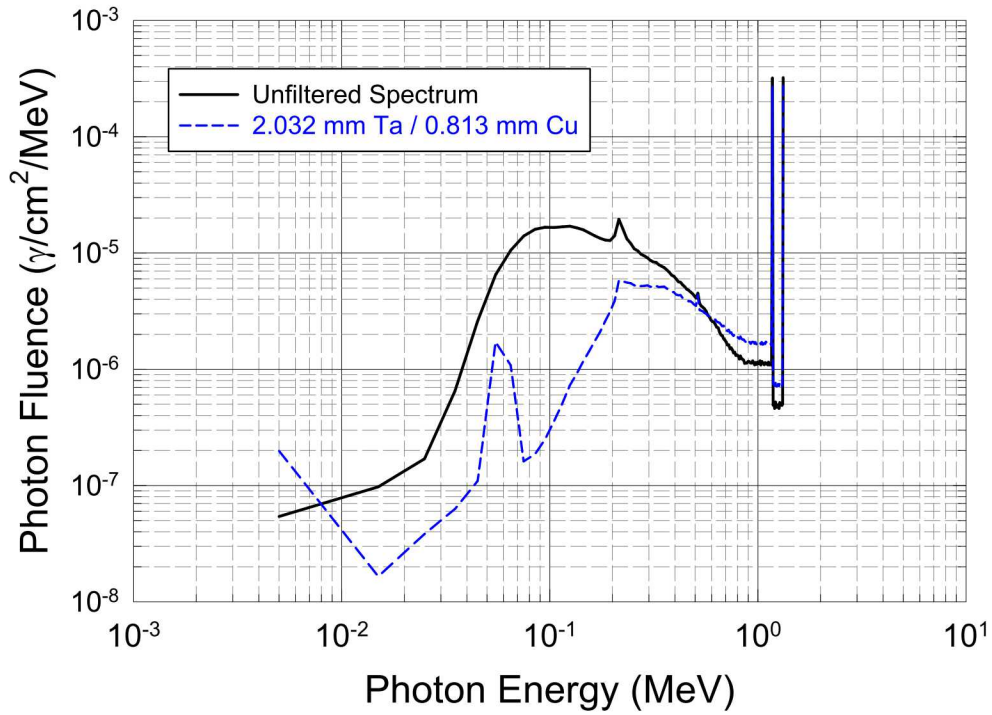


Figure 8 – Photon Spectrum with 2.032 mm Ta / 0.813 mm Cu Filter

From the figures above, it appears that suppression (or filtering) of photons with energy less than ~ 300 keV is responsible for the improvement (that is, reduction) in the DEF in the active silicon layer. Research into photon spectrum hardening metrics revealed that the most (if not all) are related to x-ray machines and medical linear accelerators rather than gamma sources. Given the lack of metrics for photon spectrum hardness, the integral ratio of photon fluence below a photon energy cutoff to the total photon fluence were examined for the spectra discussed above. Three different cutoff energies ($h\nu < 100$ keV, $h\nu < 200$ keV, and $h\nu < 300$ keV) were selected to evaluate their correlation to the DEF in the active silicon layer of the silicon sensor. These ratios are displayed in Table 5 for the unfiltered spectrum as well as three of the filter boxes considered.

Table 5 – Photon Spectral Parameters

Filter Box Details	DEF in Active Silicon Layer	$\frac{\Phi_{h\nu < 100 \text{ keV}}}{\Phi_{\text{Total}}}$	$\frac{\Phi_{h\nu < 200 \text{ keV}}}{\Phi_{\text{Total}}}$	$\frac{\Phi_{h\nu < 300 \text{ keV}}}{\Phi_{\text{Total}}}$
None	2.02	0.0547	0.1772	0.2784
1.524 mm W / 0.813 mm Cu	1.20	0.0047	0.0190	0.0734
1.587 mm Pb / 0.813 mm Cu	1.22	0.0125	0.0293	0.0907
2.032 mm Ta / 0.813 mm Cu	1.19	0.0045	0.0217	0.0834

Examining the table, there is very little difference between the DEF in the active silicon layer and the ratios for the 1.524 mm W / 0.813 mm Cu filter box and the 2.032 mm Ta / 0.813 mm Cu filter

box. The unfiltered spectrum ratios are very different from the ratios for the spectra inside the filter boxes.

The guidance in ASTM Standard E1249-15 states that, by using an appropriate filter box and correct device under test orientation, the DEF contributes no more than 20% to the dosimetry error [2]. Given the uncertainties in the tallies, there is little to no difference in the DEF in the active silicon layer for any of the three filter boxes in Table 5. Thus, a “good” filter box configuration for Co-60 gammas will produce integral metric ratios like these filters – particularly when compared to the DEF in the active silicon layer computed for the current filter box configuration used by the RML (see Table 2).

To understand the shape of the photon spectra inside the filter boxes at a deeper level, the photon attenuation cross sections for lead and tungsten are plotted with the spectra from their respective filter boxes in Figure 9. A quick look at the figure reveals that the shapes of the photon spectra have features that can be explained by the k-edges of the total photon attenuation cross sections for both lead and tungsten. While it may seem counter-intuitive, the lower k-edge energy (69.5 keV) for tungsten seems to provide better filtering than the more energetic k-edge energy (88.0 keV) of lead. However, the greater density of tungsten (19.3 g/cm^3) as compared to lead (11.35 g/cm^3) may be a more significant factor in the filtering of lower energy photons.

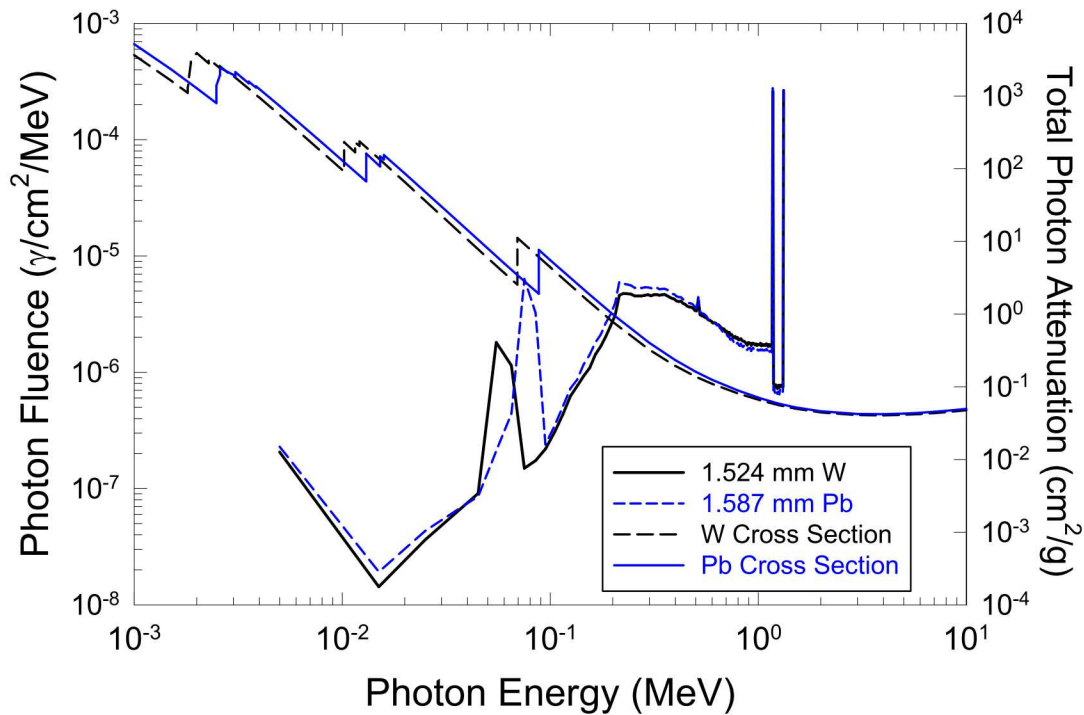


Figure 9 – Filter Box Spectra with Photon Attenuation Cross Sections

4. SUMMARY AND CONCLUSIONS

Based on a previous study [3] and the work presented above, the low energy photon filter box in use at the GIF can be improved. DePriest *et al.* suggested that adding lead to the current design while substituting copper for aluminum may improve the performance of the filter box. Both suggestions were found to improve the DEF in the active silicon layer of the sensor. This work shows that tungsten and tantalum both provide a reasonable alternative to the current lead design. While there is a desire to move away from lead in the filter box design due to its general toxicity, the potential issues with the machinability of tungsten and the expense of tantalum mean that lead should be included in any experimental study. The results for the filter boxes with bismuth did not really show improvement over the current lead/aluminum design.

This work has completed the planned radiation transport calculations to examine additional tungsten/copper, lead/copper, tantalum/copper, and bismuth/copper filter box designs called for at the 16th International Symposium on Reactor Dosimetry. The completion of this study means that filter box designs can be finalized and constructed for a set of experimental measurements. The experimental series should determine the effectiveness the various photon filters in the GIF using the method described in ASTM Standard E1250-15 [8]. The test method uses an ionization chamber technique (known as the Kerris chamber method) to determine a figure of merit for the Co-60 radiation field under investigation. The test method recommends the iterative use of the Kerris chamber method to assess the effectiveness of filter box designs to produce an irradiation environment with a suitable figure of merit for silicon electronic parts testing in a Co-60 field.

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APPENDIX A: SAMPLE GIF CELL 3 MODEL

GIF Cell #3 -- Filter Box Optimization Testing

```

C
C *****
C *          MCNP input file for new GIF Cell #3 photon dosimetry.          *
C *=====*
C * Versions:                                                                *
C *   Ver   Update   Programmer   Description                               *
C *   ---   -
C *   v1.0  10/03/01  R DePriest   Model of GIF Cell #3 for dosimetry calcs *
C *   v1.1  10/04/01  R DePriest   Add pool under the source                 *
C *   v1.2  10/05/01  R DePriest   Add Shutters to N and E Walls             *
C *   v1.3  10/15/01  R DePriest   Add "Viewing slices" to N and E Walls;    *
C *                                     Adjusted width of pool; Add Elevator   *
C *                                     Volume source in Steel Casing          *
C *   v1.4  10/24/01  R DePriest   Divided Main Cell so that photon imp's are *
C *                                     increased closer to the detectors        *
C *   v1.5  11/01/01  R DePriest   More changes to importances of cells      *
C *   v2.0  11/07/01  R DePriest   IMP:P=1 in most cells; Source biasing     *
C *   v3.0  11/15/01  R DePriest   Point Detectors; no source bias          *
C *   v4.0  03/31/03  R DePriest   12" source; lead boxes @ 13.75, 40.75, and *
C *                                     176 inches from source                  *
C *   v4.1  04/01/03  R DePriest   12" source; ion chambers @ 13.75, 40.75, *
C *                                     and 176 inches from source              *
C *   V4.2  04/06/06  SNJ & KRD   Modified to run w/ WWG for dose tallies    *
C *                                     outside Cell3 Walls                   *
C *                                     Added Cell Door (w/o windows) of       *
C *                                     2(1/8" SS) +(1/8 Pb) thick              *
C *   V4.3  09/28/06  R DePriest   Ceiling in the maze changed to correct    *
C *                                     height (243.84 cm). Ion chamber detectors *
C *                                     and cylindrical men removed. Detectors  *
C *                                     placed at location as of 9/28/06, in the *
C *                                     "old" location, and throughout the maze. *
C *   V5.0  02/17/17  R DePriest   Detectors all removed. New detectors based *
C *                                     on silicon sensor in various filter box  *
C *                                     designs.                               *
C *                                     - Co-60 Filter Box Optimization (Cont.) *
C *                                     - 0.1524 W / 0.0686 Cu                  *
C *=====*
C * CONFIGURATION:                                                            *
C *   - 5.48 W x 9.14 L x 4.11 H (m) with origin at Center-floor of Cell    *
C *   - Cell 3 orientation: -X(south), +X(north), -Y(east), +Y(west)         *
C *   - maze on north-east corner of Cell 3 with 4.11m ceiling throughout    *
C *   - Co-60 Cylindrical Source (made of Co, but density is mix of SS/Co)   *
C *   - Source bottom is located 2" from front of elevator at x= 67.945      *
C *     y=231.5 z=10.16 (R=0.56642, H=30.48);                               *
C *   - Cell, surface, detector Conventions:                                *
C *                                     MCNP Cells      # 1-299                *
C *                                     X-plane (s-n)    # 100-199              *
C *                                     Y-plane (e-w)    # 200-299              *
C *                                     Z-plane (d-u)    # 300-399              *
C *                                     Angular surfaces # 400-499              *
C *                                     Tally/detectors  # 500-599              *
C *                                     Macrobodyies    # 600-699              *
C *                                     Void            # 900-999              *
C *=====*
C
C *****
C *                                     CELL CARDS                            *
C *****
C ---+---+---+---+---+---+---+---+---+---+---+---+---+---+---+---+---+---+

```

C Irradiation Cell #3 and MAZE									
1	2	-1.0245e-3	110	-100	210	-200	310	-300	
			610	650	1503				IMP:P=1 \$Main component
2	2	-1.0245e-3	121	-100	-210	224	310	-340	IMP:P=1 \$Inner hall of MAZE
C									
2002	1	-2.27600	121	-100	-210	224	340	-300	IMP:P=1 \$Lower ceiling level--
cell 2									
C									
3	2	-1.0245e-3	100	-123	224	-223	310	-340	IMP:P=1 \$East hall of MAZE
C									
2003	1	-2.27600	100	-123	224	-223	340	-300	IMP:P=1 \$Lower ceiling level--
cell 3									
C									
4	2	-1.0245e-3	122	-123	223	-221	310	-340	IMP:P=1 \$Outer hall of MAZE
C									
2004	1	-2.27600	122	-123	223	-221	340	-300	IMP:P=1 \$Lower ceiling level--
cell 4									
C									
5	2	-1.0245e-3	123	-125	222	-221	310	-340	IMP:P=1 \$Entrance
C									
2005	1	-2.27600	123	-125	222	-221	340	-300	IMP:P=1 \$Lower ceiling level--
cell 5									
C									
80	16	-9.0326667	125	-124	222	-221	310	-340	IMP:P=1 \$Door to Entrance
C									
2080	1	-2.27600	125	-124	222	-221	340	-300	IMP:P=1 \$Lower ceiling level--
cell 80									
C									
C Shutters									
6	2	-1.0245e-3	-400	-401	-210	216	-410	-411	IMP:P=1 \$Air Cutout (N window)
7	LIKE 6 BUT TRCL=5 \$Air Cutout (S window)								
8	2	-1.0245e-3	100	-106	-402	-403	-412	-413	IMP:P=1 \$Air Cutout (N wall)
9	3	-7.82100	-404	400	-210	216	-410	-411	IMP:P=1 \$Left Steel (N window)
10	LIKE 9 BUT TRCL=5 \$Left Steel (S window)								
11	3	-7.82100	401	-405	-210	216	-410	-411	IMP:P=1 \$Right Steel (N window)
12	LIKE 11 BUT TRCL=5 \$Right Steel (S window)								
13	3	-7.82100	100	-106	402	-406	-412	-413	IMP:P=1 \$Left Steel (N wall)
14	3	-7.82100	100	-106	403	-407	-412	-413	IMP:P=1 \$Right Steel (N wall)
15	3	-7.82100	-404	-405	-216	217	-410	-411	IMP:P=1 \$Shutter (N window)
16	LIKE 15 BUT TRCL=5 \$Shutter (S window)								
17	3	-7.82100	106	-107	-406	-407	-412	-413	IMP:P=1 \$Shutter (N wall)
18	3	-7.82100	-404	-405	-210	217	410	-414	IMP:P=1 \$Bottom Steel (N window)
19	LIKE 18 BUT TRCL=5 \$Bottom Steel (S window)								
106	3	-7.82100	-404	-405	-210	217	411	-415	IMP:P=1 \$Top Steel (N window)
107	LIKE 106 BUT TRCL=5 \$Top Steel (S window)								
108	3	-7.82100	100	-106	-406	-407	412	-416	IMP:P=1 \$Bottom Steel (N wall)
109	3	-7.82100	100	-106	-406	-407	413	-417	IMP:P=1 \$Top Steel (N wall)
C "Viewing Slices"									
90	10	-2.50000	130	-131	-217	218	330	-331	IMP:P=1 \$Glass behind shutter
91	LIKE 90 BUT TRCL=5								
92	2	-1.0245e-3	130	-131	-218	219	330	-331	IMP:P=1 \$Air behind glass
93	LIKE 92 BUT TRCL=5								
94	10	-2.50000	130	-131	-219	226	330	-331	IMP:P=1 \$Glass behind air
95	LIKE 94 BUT TRCL=5								
96	12	-0.86000	130	-131	-226	227	330	-331	IMP:P=1 \$Oil behind glass
97	LIKE 96 BUT TRCL=5								
98	13	-6.20000	130	-131	-227	228	330	-331	IMP:P=1 \$Pb-glass
99	LIKE 98 BUT TRCL=5								
190	10	-2.50000	130	-131	-228	215	330	-331	IMP:P=1 \$Glass to back of wall
191	LIKE 190 BUT TRCL=5								

192	10	-2.50000	107	-132	229	-230	330	-331	IMP:P=1	\$Glass behind shutter
193	2	-1.0245e-3	132	-133	229	-230	330	-331	IMP:P=1	\$Air behind glass
194	10	-2.50000	133	-134	229	-230	330	-331	IMP:P=1	\$Glass behind air
195	12	-0.86000	134	-135	229	-230	330	-331	IMP:P=1	\$Oil behind glass
196	13	-6.20000	135	-136	229	-230	330	-331	IMP:P=1	\$Pb-glass
197	10	-2.50000	136	-105	229	-230	330	-331	IMP:P=1	\$Glass to back of wall
C South Wall Sections										
20	1	-2.27600	-110	111	211	-201	310	-300	IMP:P=1	\$First concrete
21	11	-2.55325	-111	112	212	-202	310	-300	IMP:P=1	\$First rebar
22	1	-2.27600	-112	113	213	-203	310	-300	IMP:P=1	\$Second concrete
23	11	-2.55325	-113	114	214	-204	310	-300	IMP:P=1	\$Second rebar
24	1	-2.27600	-114	115	215	-205	310	-300	IMP:P=1	\$Final concrete
C West Wall Sections										
30	1	-2.27600	110	-100	200	-201	310	-300	IMP:P=1	\$First concrete
31	11	-2.55325	111	-101	201	-202	310	-300	IMP:P=1	\$First rebar
32	1	-2.27600	112	-102	202	-203	310	-300	IMP:P=1	\$Second concrete
33	11	-2.55325	113	-103	203	-204	310	-300	IMP:P=1	\$Second rebar
34	1	-2.27600	114	-104	204	-205	310	-300	IMP:P=1	\$Final concrete
C North Wall and MAZE Sections										
40	1	-2.27600	100	-101	-201	223	310	-300		
			#8 #13 #14 #108 #109						IMP:P=1	\$First concrete
41	11	-2.55325	101	-102	-202	223	310	-300		
			#8 #13 #14 #108 #109						IMP:P=1	\$First rebar
42	1	-2.27600	102	-122	-221	223	310	-300	IMP:P=1	\$Second concrete
43	1	-2.27600	102	-103	-203	221	310	-300		
			#8 #13 #14 #17 #108 #109 #192							
			#193 #194 #195 #196						IMP:P=1	\$Second concrete
44	11	-2.55325	103	-104	-204	221	310	-300		
			#196 #197						IMP:P=1	\$Second rebar
45	1	-2.27600	104	-105	-205	221	310	-300		
			#197						IMP:P=1	\$Final concrete
46	1	-2.27600	105	-124	221	-220	310	-300	IMP:P=1	\$Maze wall
47	1	-2.27600	123	-124	225	-222	310	-300	IMP:P=1	\$Maze wall
48	1	-2.27600	121	-123	225	-224	310	-300	IMP:P=1	\$Maze wall
49	1	-2.27600	120	-121	225	-215	310	-300	IMP:P=1	\$Maze wall
C East Wall Sections										
50	1	-2.27600	110	-121	-210	211	310	-300		
			#6 #7 #9 #10 #11 #12 #18							
			#19 #106 #107						IMP:P=1	\$First concrete
51	11	-2.55325	111	-121	-211	212	310	-300		
			#6 #7 #9 #10 #11 #12 #18							
			#19 #106 #107						IMP:P=1	\$First rebar
52	1	-2.27600	112	-121	-212	213	310	-300		
			#6 #7 #9 #10 #11 #12 #15 #16 #18							
			#19 #106 #107 #90 #91 #92 #93 #94							
			#95 #96 #97 #98 #99						IMP:P=1	\$Second concrete
53	11	-2.55325	113	-121	-213	214	310	-300		
			#98 #99 #190 #191						IMP:P=1	\$Second rebar
54	1	-2.27600	114	-121	-214	215	310	-300		
			#190 #191						IMP:P=1	\$Final concrete
C Ceiling Sections										
60	1	-2.27600	115	-121	215	-205	300	-301	IMP:P=1	\$First concrete
61	11	-2.55325	115	-121	215	-205	301	-302	IMP:P=1	\$First rebar
62	1	-2.27600	115	-121	215	-205	302	-303	IMP:P=1	\$Second concrete
63	11	-2.55325	115	-121	215	-205	303	-304	IMP:P=1	\$Second rebar
64	1	-2.27600	115	-121	215	-205	304	-305	IMP:P=1	\$Final concrete
65	1	-2.27600	121	-105	225	-205	300	-301	IMP:P=1	\$First concrete
66	11	-2.55325	121	-105	225	-205	301	-302	IMP:P=1	\$First rebar
67	1	-2.27600	121	-105	225	-205	302	-303	IMP:P=1	\$Second concrete
68	11	-2.55325	121	-105	225	-205	303	-304	IMP:P=1	\$Second rebar
69	1	-2.27600	121	-105	225	-205	304	-305	IMP:P=1	\$Final concrete
160	1	-2.27600	105	-124	225	-220	300	-301	IMP:P=1	\$First concrete
161	11	-2.55325	105	-124	225	-220	301	-302	IMP:P=1	\$First rebar

162	1	-2.27600	105	-124	225	-220	302	-303	IMP:P=1	\$Second concrete
163	11	-2.55325	105	-124	225	-220	303	-304	IMP:P=1	\$Second rebar
164	1	-2.27600	105	-124	225	-220	304	-305	IMP:P=1	\$Final concrete
165	1	-2.27600	120	-121	-215	225	300	-305	IMP:P=1	\$Concrete add-in
C Floor Sections										
70	1	-2.27600	115	-121	215	-205	-310	311		
			600						IMP:P=1	\$First concrete
71	11	-2.55325	115	-121	215	-205	-311	312		
			600						IMP:P=1	\$First rebar
72	1	-2.27600	115	-121	215	-205	-312	313		
			600						IMP:P=1	\$Second concrete
73	11	-2.55325	115	-121	215	-205	-313	314		
			600						IMP:P=1	\$Second rebar
74	1	-2.27600	115	-121	215	-205	-314	315		
			600						IMP:P=1	\$Final concrete
75	1	-2.27600	121	-105	225	-205	-310	311	IMP:P=1	\$First concrete
76	11	-2.55325	121	-105	225	-205	-311	312	IMP:P=1	\$First rebar
77	1	-2.27600	121	-105	225	-205	-312	313	IMP:P=1	\$Second concrete
78	11	-2.55325	121	-105	225	-205	-313	314	IMP:P=1	\$Second rebar
79	1	-2.27600	121	-105	225	-205	-314	315	IMP:P=1	\$Final concrete
170	1	-2.27600	105	-124	225	-220	-310	311	IMP:P=1	\$First concrete
171	11	-2.55325	105	-124	225	-220	-311	312	IMP:P=1	\$First rebar
172	1	-2.27600	105	-124	225	-220	-312	313	IMP:P=1	\$Second concrete
173	11	-2.55325	105	-124	225	-220	-313	314	IMP:P=1	\$Second rebar
174	1	-2.27600	105	-124	225	-220	-314	315	IMP:P=1	\$Final concrete
175	1	-2.27600	120	-121	-215	225	-310	315	IMP:P=1	\$Concrete add-in
C										
C										
C										
C Pool, sources, and elevator										
C										
600	8	-1.00000	-600						IMP:P=0.25	\$Pool under source
610	9	-8.36050	-610						IMP:P=1	\$Co-source
650	5	-2.70000	-650						IMP:P=1	\$Aluminum elevator
C Voids										
920	0	-900	-115		-205	215	-305	315	IMP:P=1	\$Void Outside S wall
930	0	-900			205		-305	315	IMP:P=1	\$Void Outside W wall
940	0	-900	105		220	-205	-305	315	IMP:P=1	\$Void Outside N wall
941	0	-900	124		-220	225	-305	315	IMP:P=1	\$Void Outside N wall
950	0	-900	120		-225		-305	315	IMP:P=1	\$Void Outside E wall
951	0	-900	-120		-215		-305	315	IMP:P=1	\$Void Outside E wall
960	0	-900					305		IMP:P=1	\$Void Above ceiling
970	0	-900					600	-315	IMP:P=1	\$Void Below Floor
C										
C Detectors (1500-2000)										
C										
C										
1501	2	-1.0245e-3	-1501	1504	1510	1511	1512			
			1513	1514	1515	1516	1517	1518		
			1519	1520	1521	1522	1523	1524	IMP:P=1	\$Air box
C										
1502	29	-8.96	-1502	1501					IMP:P=1	\$Cu - 0.0686 cm
C										
1503	209	-19.3	-1503	1502					IMP:P=1	\$W - 0.1524 cm
C										
1504	2	-1.0245e-3	-1504						IMP:P=1	\$Sphere Box 5
C										
C										
C CMO7 Stack for Box 6 - Solder on "bottom"										
C										
1510	201	-8.67	-1510						IMP:P=1	\$Solder
1511	202	-8.94	-1511						IMP:P=1	\$Cu - 1
1512	203	-8.90	-1512						IMP:P=1	\$Ni - 1


```

210 py -274.00 $East wall (use on MAZE too)
211 py -281.50 $Distance to rebar in E wall
212 py -291.50 $Rebar depth 10cm~4inches
213 py -438.50 $Second rebar
214 py -448.50 $Rebar depth 10cm~4inches
215 py -456.00 $Outside E wall
216 py -329.88 $Depth of shutter
C Y-planes for "viewing slices"
217 py -332.42 $Shutter is 1"=2.54 cm thick
218 py -334.96 $Glass is 1"=2.54 cm thick
219 py -337.83 $Air layer 2.87 cm thick
226 py -355.61 $Glass is 7"=17.78 cm thick
227 py -393.20 $Oil is 14.8"=37.59 cm thick
228 py -441.46 $Pb-glass 19"=48.26 cm thick
229 py 65.25 $Edge of glass
230 py 180.52 $Edge of glass
C Y-planes for MAZE
220 py -91.00 $Outside of MAZE wall (W)
221 py -136.72 $W wall of MAZE entrance
222 py -227.72 $W end of outer MAZE wall
223 py -517.00 $W end of inner MAZE wall
224 py -608.00 $E end of MAZE
225 py -699.00 $Outside of MAZE wall (E)
C ---+---+---+---+---+---+---+---+---+---+---+---+
C Z-planes for CEILING
300 pz 411.00 $Ceiling
301 pz 418.50 $Distance to rebar in ceiling
302 pz 428.50 $Rebar depth 10cm~4inches
303 pz 530.50 $Second rebar
304 pz 540.50 $Rebar depth 10cm~4inches
305 pz 548.00 $Outside of ceiling
C Z-planes for FLOOR
310 pz 0.00 $Floor
311 pz -7.50 $Distance to rebar in floor
312 pz -17.50 $Rebar depth 10cm~4inches
313 pz -62.50 $Second rebar
314 pz -72.50 $Rebar depth 10cm~4inches
315 pz -80.00 $Outside of floor
C Z-planes for "viewing slices"
330 pz 42.90 $Bottom of glass
331 pz 218.64 $Top of glass
C Z-planes for maze ceiling
340 pz 243.84 $Ceiling in the maze section
C Angular planes for shutters
400 p 0.00 -274.00 0.00 0.00 -274.00 50.00
    45.25 -329.88 0.00
401 p 205.74 -274.00 0.00 205.74 -274.00 50.00
    160.49 -329.88 0.00
402 p 457.00 20.00 0.00 457.00 20.00 50.00
    512.88 65.25 0.00
403 p 457.00 225.74 0.00 457.00 225.74 50.00
    512.88 180.52 0.00
404 p -5.08 -274.00 0.00 -5.08 -274.00 50.00
    40.17 -329.88 0.00
405 p 210.82 -274.00 0.00 210.82 -274.00 50.00
    165.57 -329.88 0.00
406 p 457.00 14.92 0.00 457.00 14.92 50.00
    512.88 60.17 0.00
407 p 457.00 230.82 0.00 457.00 230.82 50.00
    512.88 185.60 0.00
410 p 0.00 -274.00 20.32 50.00 -274.00 20.32
    0.00 -329.88 42.90
411 p 0.00 -274.00 241.22 50.00 -274.00 241.22

```

		0.00	-329.88	218.64				
412	p	457.00	0.00	20.32	457.00	50.00	20.32	
		512.88	0.00	42.90				
413	p	457.00	0.00	241.22	457.00	50.00	241.22	
		512.88	0.00	218.64				
414	p	0.00	-274.00	15.24	50.00	-274.00	15.24	
		0.00	-329.88	37.82				
415	p	0.00	-274.00	246.30	50.00	-274.00	246.30	
		0.00	-329.88	223.72				
416	p	457.00	0.00	15.24	457.00	50.00	15.24	
		512.88	0.00	37.82				
417	p	457.00	0.00	246.30	457.00	50.00	246.30	
		512.88	0.00	223.72				
C								
C								
C	Detectors							
C								
1501	RPP	62.945	72.945	126.50	136.50	20.4	30.4	\$Air box 1 meter
	from source							
1502	RPP	62.8764	73.0136	126.4314	136.5686	20.3314	30.4686	\$0.0686 Cu box
1503	RPP	62.72400	73.16600	126.27900	136.72100	20.17900	30.62100	\$0.1524 W box
C								
1504	S	70.0000	131.500000	25.400	1.0			\$Detector sphere
C								
1510	RCC	66.0000	131.500000	25.400				
		0.000000	0.060000	0.000	1.128371			\$Solder
1511	RCC	66.0000	131.560000	25.400				
		0.000000	0.001500	0.000	1.128371			\$Cu layer - 1
1512	RCC	66.0000	131.561500	25.400				
		0.000000	0.000500	0.000	1.128371			\$Ni layer - 1
1513	RCC	66.0000	131.562000	25.400				
		0.000000	0.000070	0.000	1.128371			\$Au layer - 1
1514	RCC	66.0000	131.562070	25.400				
		0.000000	0.036000	0.000	1.128371			\$BT Laminate
1515	RCC	66.0000	131.598070	25.400				
		0.000000	0.001500	0.000	1.128371			\$Cu layer - 2
1516	RCC	66.0000	131.599570	25.400				
		0.000000	0.000500	0.000	1.128371			\$Ni layer - 2
1517	RCC	66.0000	131.600070	25.400				
		0.000000	0.000070	0.000	1.128371			\$Au layer - 2
1518	RCC	66.0000	131.600140	25.400				
		0.000000	0.003000	0.000	1.128371			\$Ablebond 8361J
1519	RCC	66.0000	131.603140	25.400				
		0.000000	0.030000	0.000	1.128371			\$Si (p-type)
1520	RCC	66.0000	131.633140	25.400				
		0.000000	0.000020	0.000	1.128371			\$SiO2 layer
1521	RCC	66.0000	131.633160	25.400				
		0.000000	0.000025	0.000	1.128371			\$Active Si layer
1522	RCC	66.0000	131.633185	25.400				
		0.000000	0.000085	0.000	1.128371			\$W layer
1523	RCC	66.0000	131.633270	25.400				
		0.000000	0.000838	0.000	1.128371			\$SiO2 passivation layer
1524	RCC	66.0000	131.634108	25.400				
		0.000000	0.086600	0.000	1.128371			\$Plastic Encapsulation
C								
C								
C								
C	Macrobody for pool, source, and elevator							
C								
C								
600	rpp	-135.89	135.89	189.00	456.00			
		-600.00	0.00					\$Pool depth 6.0 m


```

610   rcc  67.945 196.62 10.16 0 0 30.48 0.56642 $Source
650   rpp    2.54 133.35 191.54 271.46
      5.08 10.16                                $Elevator
C
900   RPP  -1638 1638 -1698 1698 -1600 1600

C *****
C *                                     DATA CARDS *
C *****
MODE P E
PHYS:P 100.0 0
NPS    5.0e10
RAND   GEN=2 STRIDE=352917
PRDMP  j 1.0E9 j 2 1.0e9
C *****
C * SOURCE CARDS *
C *****
SDEF  CEL=610 ERG=D1 POS=67.945 196.62 25.4 AXS=0 0 1
      RAD=D2 EXT=D3
SC1   Cobalt-60 Single Pin Source
SI1   L 1.173 1.322
SP1   D 1.0 1.0
SI2   0 0.56642
SI3   15.24
C
C  MPlot TAL=126  FREQ=250000  FREE F XLIMS=0 52  PLINEAR
C
C *****
C * TRANSFORMATIONS *
C *****
TR5   -285.74      0.00      0.00
C
C *****
C * MATERIAL CARDS *
C *****
M1     8000.84p -0.503507      14000.84p -0.320735      $Concrete
      13000.84p -4.74581e-2      26000.84p -1.99938e-2      $Boldt's model with
      20000.84p -6.83329e-2      6000.84p -9.51764e-4      $Kr->Fe
      11000.84p -1.52287e-2      19000.84p -1.23728e-2      $Zn->Ca
      1000.84p -9.51619e-3      12000.84p -1.90351e-3
C
M11    8000.84p -0.417606      14000.84p -0.266016      $Reinforced concrete
      13000.84p -3.93610e-2      26000.84p -0.165085      $Values obtain from
      20000.84p -5.66749e-2      6000.84p -2.28933e-2      $Excel sheet concrete.xls
      11000.84p -1.26306e-2      19000.84p -1.02619e-2
      1000.84p -7.89267e-3      12000.84p -1.57876e-3
C
M2     7000.84p 0.784484      8000.84p 0.210722      $N & O components of air
      6000.84p 0.000165      18000.84p 0.004629      $C & Ar components of air
C
M3     26000.84p -0.990001      6000.84p -0.009999      $Carbon Steel from KENO
C
M5     13000.84p 1.000000
C
M8     1000.84p 0.666667      8000.84p 0.333333      $Water in pool
C
M9     27000.84p 1.000000
C
M10    8000.84p 0.666667      14000.84p 0.333333      $Si[O2] -> Glass
C
M12    1000.84p 0.654310      6000.84p 0.345690      $BC-517H Mineral Oil (Bicron)
C
M13    8000.84p 0.531667      14000.84p 0.063333

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```

      82000.84p    0.405000                                $Pb-glass (concrete.xls)
C
M14    82000.84p    1.000000                                $Pb for box
C
M15    14000.84p    1.000000                                $Si for dose measurement
C
M16    82000.84p  -0.4188513    26000.84p  -0.58114835    $ 1/3 thickness Pb, 2/3
thickness Fe ...M10=9.032667g/cc
C
C
C
C
C Copper @ 8.96 g/cc
C
C Summary of MatMCNP (Version 3.0) Calculations:
C
C Isotope  Number Fraction    Weight Fraction        Atoms/b-cm
C Cu-63      0.691500          0.684792            0.0515083
C Cu-65      0.308500          0.315208            0.0229795
C
C The total compound atom density (atom/b-cm):  0.0744878
C
M29      29000.84p    1.000000
C
C
C
C Tantalum from Nuclear Wallet Cards - Electronic Version
C Isotope   atomic abundance    delta (MeV)
C Ta-180m    0.01201             -48.8594
C Ta-181     99.98799             -48.4419
C
C Atomic Weight:  180.94788 g/mol
C Density:  16.4 g/cc
C
C Summary of MatMCNP (Version 3.0) Calculations:
C
C Isotope  Number Fraction    Weight Fraction        Atoms/b-cm
C Ta-180    0.000120          0.000119            0.0000066
C Ta-181    0.999880          0.999881            0.0545744
C
C The total compound atom density (atom/b-cm):  0.0545810
C
M73      73000.84p    1.000000
C
C To convert a particle flux to rad[Material]
C use FM  5.3316296E-11 73   -4   1 for neutrons
C or FM  5.3316296E-11 73   -5  -6 for photons.
C
C
C
C Bismuth from Nuclear Wallet Cards - Electronic Version
C Isotope   atomic abundance    delta (MeV)
C Bi-209    100.0%             -18.2593
C
C Atomic Weight:  208.98040 g/mol
C Density:  9.747 g/cc
C
C Summary of MatMCNP (Version 3.0) Calculations:
C
C Isotope  Number Fraction    Weight Fraction        Atoms/b-cm
C Bi-209    1.000000          1.000000            0.0280877

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C
C The total compound atom density (atom/b-cm): 0.0280877
C
M83      83000.84p    1.000000
C
C To convert a particle flux to rad[Material]
C use FM 4.6164478E-11 83 -4 1 for neutrons
C or FM 4.6164478E-11 83 -5 -6 for photons.
C
C
C
C Solder - Sn/Pb - 63/37
C
C Material extracted from CMOS7 stack-up
C Atom fractions in the stack-up deck from C. D. Peters
C
C Summary of MatMCNP (Version 3.0) Calculations:
C
C Isotope Number Fraction Weight Fraction Atoms/b-cm
C Sn-112 0.007258 0.005760 0.0002688
C Sn-114 0.004938 0.003989 0.0001829
C Sn-115 0.002544 0.002073 0.0000942
C Sn-116 0.108792 0.089431 0.0040287
C Sn-117 0.057464 0.047645 0.0021280
C Sn-118 0.181221 0.151540 0.0067109
C Sn-119 0.064273 0.054203 0.0023801
C Sn-120 0.243772 0.207306 0.0090272
C Sn-122 0.034643 0.029952 0.0012829
C Sn-124 0.043322 0.038072 0.0016043
C Pb-204 0.003525 0.005099 0.0001305
C Pb-206 0.060677 0.088642 0.0022470
C Pb-207 0.055642 0.081681 0.0020605
C Pb-208 0.131929 0.194605 0.0048855
C
C The total compound atom density (atom/b-cm): 0.0370314
C
M201     50000.84p    0.748227
        82000.84p    0.251773
C
C To convert a particle flux to rad[Material]
C use FM 6.8424849E-11 201 -4 1 for neutrons
C or FM 6.8424849E-11 201 -5 -6 for photons.
C
C
C Copper from Nuclear Wallet Cards - Electronic Version
C Isotope atomic abundance delta (MeV)
C Cu-63 69.15% -65.5792
C Cu-65 30.85% -67.2633
C
C Atomic Weight: 63.546 g/mol
C Density: 8.94 g/cc
C
C Summary of MatMCNP (Version 3.0) Calculations:
C
C Isotope Number Fraction Weight Fraction Atoms/b-cm
C Cu-63 0.691500 0.684792 0.0585858
C Cu-65 0.308500 0.315208 0.0261370
C
C The total compound atom density (atom/b-cm): 0.0847227
C
M202     29000.84p    1.000000
C
C To convert a particle flux to rad[Material]

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C use FM 1.5181860E-10 202 -4 1 for neutrons
C or FM 1.5181860E-10 202 -5 -6 for photons.
C
C
C
C Nickel from Nuclear Wallet Cards - Electronic Version
C Isotope atomic abundance delta (MeV)
C Ni-58 68.077% -60.2281
C Ni-60 26.223% -64.4725
C Ni-61 1.1399% -64.2212
C Ni-62 3.6346% -66.7458
C Ni-64 0.9255% -67.0984
C
C Atomic Weight: 58.6934 g/mol
C Density: 8.902 g/cc
C
C Summary of MatMCNP (Version 3.0) Calculations:
C
C Isotope Number Fraction Weight Fraction Atoms/b-cm
C Ni-58 0.680770 0.671978 0.0621799
C Ni-60 0.262230 0.267759 0.0239515
C Ni-61 0.011399 0.011834 0.0010412
C Ni-62 0.036346 0.038349 0.0033198
C Ni-64 0.009255 0.010080 0.0008453
C
C The total compound atom density (atom/b-cm): 0.0913376
C
M203 28000.84p 1.000000
C
C To convert a particle flux to rad[Material]
C use FM 1.6437075E-10 203 -4 1 for neutrons
C or FM 1.6437075E-10 203 -5 -6 for photons.
C
C
C Gold from Nuclear Wallet Cards - Electronic Version
C Isotope atomic abundance delta (MeV)
C Au-197 100.0% -31.1409
C
C Atomic Weight: 196.966569 g/mol
C Density: 19.3 g/cc
C
C Summary of MatMCNP (Version 3.0) Calculations:
C
C Isotope Number Fraction Weight Fraction Atoms/b-cm
C Au-197 1.000000 1.000000 0.0590087
C
C The total compound atom density (atom/b-cm): 0.0590087
C
M204 79000.84p 1.000000
C
C To convert a particle flux to rad[Material]
C use FM 4.8980243E-11 204 -4 1 for neutrons
C or FM 4.8980243E-11 204 -5 -6 for photons.
C
C
C
C BT Laminate from CMOS7 Stack
C
C Material extracted from CMOS7 stack-up
C Based on atomic data in the stack-up
C

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C   Summary of MatMCNP (Version 3.0) Calculations:
C
C   Isotope   Number Fraction   Weight Fraction   Atoms/b-cm
C   H-1       0.360518         0.042790         0.0334951
C   H-2       0.000041         0.000010         0.0000039
C   C-12      0.486645         0.687742         0.0452133
C   C-13      0.005263         0.008060         0.0004890
C   N-14      0.070427         0.116144         0.0065433
C   N-15      0.000257         0.000455         0.0000239
C   O-16      0.076661         0.144407         0.0071224
C   O-17      0.000029         0.000058         0.0000027
C   O-18      0.000158         0.000334         0.0000146
C
C   The total compound atom density (atom/b-cm): 0.0929083
C
M205   01000.84p  0.360560
        06000.84p  0.491908
        07000.84p  0.070684
        08000.84p  0.076848
C
C   To convert a particle flux to rad[Material]
C   use FM 1.1361758E-09 205 -4 1 for neutrons
C   or FM 1.1361758E-09 205 -5 -6 for photons.
C
C
C   Ablebond 8361 J from CMOS7 Stack
C
C   Material extracted from CMOS7 stack-up
C   Based on atomic data in the stack-up
C
C   Summary of MatMCNP (Version 3.0) Calculations:
C
C   Isotope   Number Fraction   Weight Fraction   Atoms/b-cm
C   H-1       0.396713         0.016453         0.0334265
C   H-2       0.000046         0.000004         0.0000038
C   C-12      0.333858         0.164865         0.0281305
C   C-13      0.003611         0.001932         0.0003043
C   O-16      0.092832         0.061103         0.0078219
C   O-17      0.000035         0.000025         0.0000030
C   O-18      0.000191         0.000141         0.0000161
C   Cl-35     0.002844         0.004093         0.0002397
C   Cl-37     0.000910         0.001384         0.0000767
C   Ag-107    0.087587         0.385321         0.0073800
C   Ag-109    0.081373         0.364678         0.0068564
C
C   The total compound atom density (atom/b-cm): 0.0842587
C
M206   01000.84p  0.396759
        06000.84p  0.337469
        08000.84p  0.093058
        17000.84p  0.003754
        47000.84p  0.168960
C
C   To convert a particle flux to rad[Material]
C   use FM 3.9700715E-10 206 -4 1 for neutrons
C   or FM 3.9700715E-10 206 -5 -6 for photons.
C
C
C
C   To convert a particle flux to rad[Material]
C   use FM 6.6316874E-10 1 -4 1 for neutrons
C   or FM 6.6316874E-10 1 -5 -6 for photons.
C

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C Silicon at 2.33 g/cc
C
C Summary of MatMCNP (Version 3.0) Calculations:
C
C Isotope Number Fraction Weight Fraction Atoms/b-cm
C Si-28 0.922230 0.918665 0.0460749
C Si-29 0.046850 0.048336 0.0023406
C Si-30 0.030920 0.032999 0.0015448
C
C The total compound atom density (atom/b-cm): 0.0499603
C
M207 14000.84p 1.000000
C
C To convert a particle flux to rad[Material]
C use FM 3.4350364E-10 207 -4 1 for neutrons
C or FM 3.4350364E-10 207 -5 -6 for photons.
C
C
C SiO2 from CMOS7 Stack
C
C Material extracted from CMOS7 stack-up
C Based on atomic data in the stack-up
C
C Summary of MatMCNP (Version 3.0) Calculations:
C
C Isotope Number Fraction Weight Fraction Atoms/b-cm
C O-16 0.665047 0.531122 0.0439132
C O-17 0.000253 0.000215 0.0000167
C O-18 0.001367 0.001228 0.0000902
C Si-28 0.307410 0.429416 0.0202984
C Si-29 0.015617 0.022594 0.0010312
C Si-30 0.010307 0.015425 0.0006806
C
C The total compound atom density (atom/b-cm): 0.0660303
C
M208 08000.84p 0.666667
14000.84p 0.333333
C
C To convert a particle flux to rad[Material]
C use FM 4.8169663E-10 208 -4 1 for neutrons
C or FM 4.8169663E-10 208 -5 -6 for photons.
C
C
C Tungsten at 19.3 g/cc
C
C Summary of MatMCNP (Version 3.0) Calculations:
C
C Isotope Number Fraction Weight Fraction Atoms/b-cm
C W-180 0.001200 0.001175 0.0000759
C W-182 0.265000 0.262271 0.0167537
C W-183 0.143100 0.142406 0.0090470
C W-184 0.306400 0.306582 0.0193710
C W-186 0.284300 0.287567 0.0179738
C
C The total compound atom density (atom/b-cm): 0.0632214
C
M209 74000.84p 1.000000
C
C To convert a particle flux to rad[Material]
C use FM 5.2477033E-11 209 -4 1 for neutrons
C or FM 5.2477033E-11 209 -5 -6 for photons.

```

```

C
C
C ABS Plastic from CMOS7 Stack
C
C Material extracted from CMOS7 stack-up
C Based on atomic data in the stack-up
C
C Summary of MatMCNP (Version 3.0) Calculations:
C
C Isotope Number Fraction Weight Fraction Atoms/b-cm
C H-1 0.515091 0.081073 0.0445688
C H-2 0.000059 0.000019 0.0000051
C C-12 0.449686 0.842750 0.0389096
C C-13 0.004864 0.009877 0.0004208
C N-14 0.030190 0.066022 0.0026122
C N-15 0.000110 0.000258 0.0000095
C
C The total compound atom density (atom/b-cm): 0.0865261
C
M210 01000.84p 0.515150
      06000.84p 0.454550
      07000.84p 0.030300
C
C To convert a particle flux to rad[Material]
C use FM 1.5066821E-09 210 -4 1 for neutrons
C or FM 1.5066821E-09 210 -5 -6 for photons.
C
C
C
C *****
C * PHOTON TALLIES *
C *****
C
F4:P 1504
FC4 Photon Fluence in the Detector Sphere (Photons/cm**2)
C
F14:P 1504
FC14 Silicon Kerma in Detector Sphere (Rad[Si])
FM14 3.4350364E-10 207 -5 -6
C
C
F104:P 1521
FM104 3.4350364E-10 207 -5 -6
FC104 Average Silicon Kerma in Si Active Region (Rad[Si])
C
C
C The collision heating tally (+F6) always applies to all particles
C in a problem according to the MCNP6 User's Manual.
C
+F106 1521
FC106 Energy Deposition in Si in Box 1 (MeV/g)
C
+F746 1522
FC746 Energy Deposition in W (MeV/g)
C
+F756 1520
FC756 Energy Deposition in SiO2 (MeV/g)
C
C
C
C
C

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